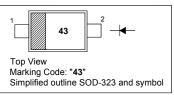
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

- · Low forward voltage
- Fast switching

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40	V
DC Blocking Voltage	V _R	40	V
Forward Continuous Current	I _F	200	mA
Peak Forward Surge Current (at tp = 8.3 ms)	I _{FSM}	600	mA
Junction Temperature	T _J	150	°C
Storage Temperature Range	Ts	- 55 to + 150	°C

Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 40 \text{ mA}$	V_{F}	-	0.38 1	V V
Reverse Current at V _R = 30 V	I _R	-	200	nA
Reverse Breakdown Voltage at I _R = 10 μA	$V_{(BR)R}$	40	-	V
Reverse Recovery Time at $I_F = I_R = 10$ mA to $I_R = 1$ mA, $R_L = 100$ Ω	t _{rr}	-	5	ns
Capacitance at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$	C _j	-	5	pF





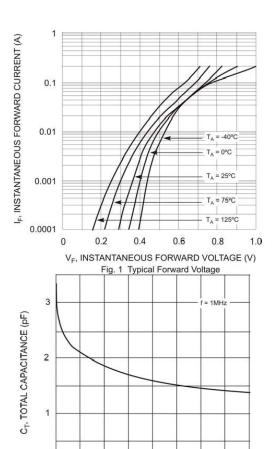
listed on the Hong Kong Stock Exchange, Stock Code: 724)

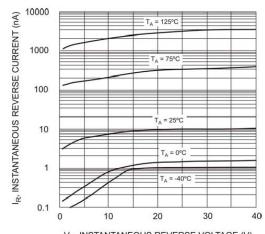






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 V_R , INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 2 Typical Reverse Characteristics



0

10

20

V_R, REVERSE VOLTAGE (V) Fig. 3 Typical Capacitance

40

SEMTECH ELECTRONICS LTD.

(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)





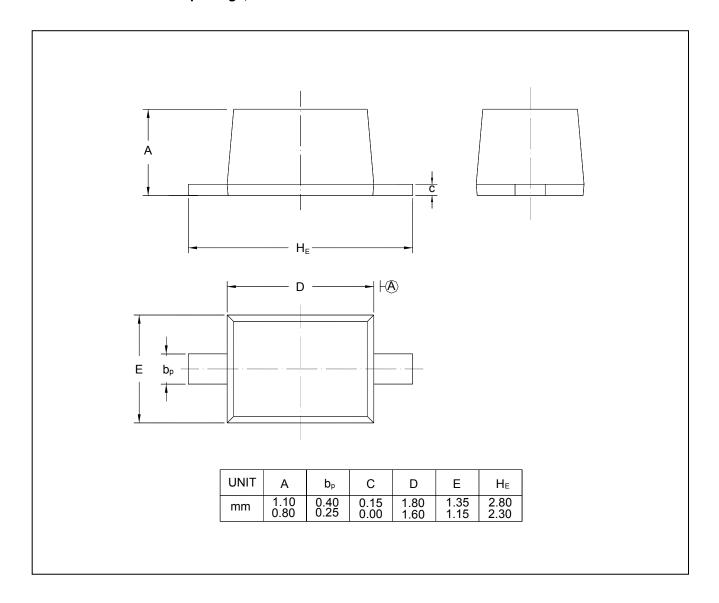


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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323





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